

#### 300V PNP HIGH VOLTAGE TRANSISTOR IN SOT23

#### **Description**

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

#### **Features**

- BV<sub>CEO</sub> > -300V
- I<sub>C</sub> = -200mA High Continuous Collector Current
- Complementary Type: FMMTA42Q
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The FMMTA92Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions

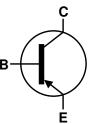
### **Mechanical Data**

- Package: SOT23
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>®3</a>
- Weight 0.008 grams (Approximate)

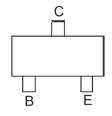




Top View



Device Symbol



Top View Pin-Out

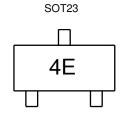
#### **Ordering Information** (Note 4)

| Orderable   | Orderable Package |         | Reel Size (inches)  | Tape Width (mm)     | Packing |         |
|-------------|-------------------|---------|---------------------|---------------------|---------|---------|
| Part Number | Package           | Marking | neer Size (Iliches) | rape widin (ililii) | Qty.    | Carrier |
| FMMTA92QTA  | SOT23             | 4E      | 7                   | 8                   | 3,000   | Reel    |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



4E = Product Type Marking Code



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic               | Symbol           | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage       | V <sub>CBO</sub> | -300  | V    |
| Collector-Emitter Voltage    | $V_{CEO}$        | -300  | V    |
| Emitter-Base Voltage         | $V_{EBO}$        | -5    | V    |
| Continuous Collector Current | I <sub>C</sub>   | -200  | mA   |

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic                                | Symbol                           | Value            | Unit |               |  |
|---|----------------------------------|------------------|------|---------------|--|
| Dower Discinstion                             | (Note 6)                         | 0                | 0.31 | W             |  |
| Power Dissipation                             | (Note 7)                         | P <sub>D</sub>   | 0.35 | VV            |  |
| Thermal Desistance Junction to Ambient        | (Note 6)<br>(Note 7)             |                  | 403  | °C/W          |  |
| Thermal Resistance, Junction to Ambient       |                                  |                  | 357  | °C/ <b>VV</b> |  |
| Thermal Resistance, Junction to Lead (Note 8) |                                  | R <sub>0JL</sub> | 350  | °C/W          |  |
| Operating and Storage Temperature Range       | T <sub>J,</sub> T <sub>STG</sub> | -55 to +150      | °C   |               |  |

### ESD Ratings (Note 8)

| Characteristic                             | Symbol  | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge – Human Body Model | ESD HBM | 4,000 | V    | 3A          |
| Electrostatic Discharge – Machine Model    | ESD MM  | 400   | V    | С           |

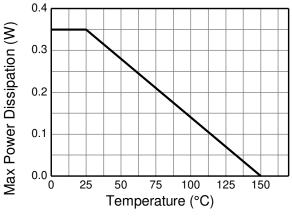
Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition.
   6. Same as Note (5), except the device is mounted on 15mm x 15mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



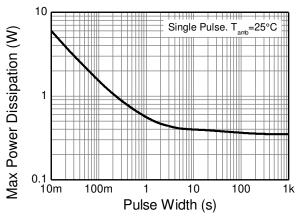
### **Thermal Characteristics and Derating Information**



400 350 350 300 250 200 D=0.5 150 D=0.1 D=0.05 100μ 1m 10m 100m 1 10 100 18 Pulse Width (s)

Figure 1. Derating Curve

Figure 2. Transient Thermal Impedance



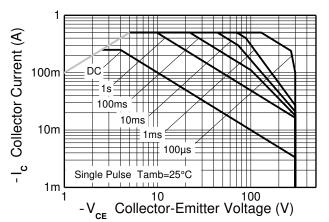


Figure 3. Pulse Power Dissipation

Figure 4. Safe Operating Area



# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

| Characteristic                                 | Symbol               | Min  | Тур | Max  | Unit | Test Condition                               |
|--|----------------------|------|-----|------|------|--|
| Collector-Base Breakdown Voltage               | $BV_CBO$             | -300 | 1   | 1    | V    | $I_{C} = -100 \mu A$                         |
| Collector-Emitter Breakdown Voltage (Note 9)   | BV <sub>CEO</sub>    | -300 | _   | _    | V    | I <sub>C</sub> = -1mA                        |
| Emitter-Base Breakdown Voltage                 | BV <sub>EBO</sub>    | -5   | _   | _    | V    | $I_E = -100 \mu A$                           |
| Collector Cutoff Current                       | I <sub>CES</sub>     | _    |     | -250 | nA   | V <sub>CE</sub> = -200V                      |
| Collector Cutoff Current                       | l                    | _    | _   | -250 | nA   | V <sub>CB</sub> = -200V                      |
| Collector Cuton Current                        | I <sub>CBO</sub>     |      |     | -230 | IIA  | V <sub>CB</sub> = -160V                      |
| Emitter Cutoff Current                         | I <sub>EBO</sub>     | _    |     | -100 | nA   | $V_{EB} = -3V$                               |
|  |                      | 25   | _   | _    |      | $I_C = -1 \text{mA}, V_{CE} = -10 \text{V}$  |
| Static Forward Current Transfer Ratio (Note 9) | $h_{FE}$             | 40   | _   | _    |      | $I_C = -10 \text{mA}, V_{CE} = -10 \text{V}$ |
|  |                      | 25   | _   | _    |      | $I_C = -30 \text{mA}, V_{CE} = -10 \text{V}$ |
| Collector-Emitter Saturation Voltage (Note 9)  | V <sub>CE(sat)</sub> | _    | _   | -0.5 | V    | $I_C = -20mA$ , $I_B = -2mA$                 |
| Base-Emitter Saturation Voltage (Note 9)       | $V_{BE(on)}$         | _    | _   | -0.9 | V    | $I_C = -20 \text{mA}, I_B = -2 \text{mA}$    |
| Output Capacitance                             | $C_{obo}$            | _    | _   | 6    | pF   | $V_{CB} = -20V$ , $f = 1MHz$                 |
| Transition Frequency                           | f <sub>T</sub>       | 50   | _   | _    | MHz  | $V_{CE} = -20V, I_{C} = -10mA,$<br>f = 20MHz |

Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300 \mu s$ . Duty cycle  $\leq 2\%$ 



# Typical Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

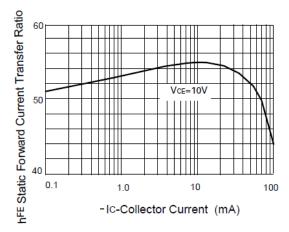


Figure 5. h<sub>FE</sub> v I<sub>C</sub>

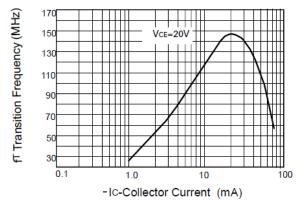


Figure 6. f<sub>T</sub> v I<sub>C</sub>

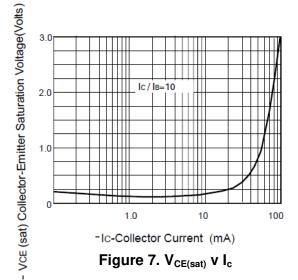


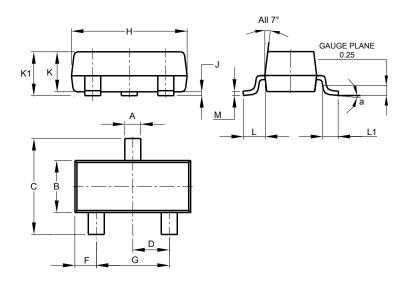
Figure 7. V<sub>CE(sat)</sub> v I<sub>c</sub>



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

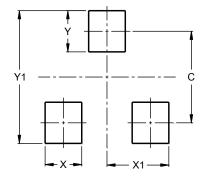


| SOT23                |       |       |       |  |  |
|----------------------|-------|-------|-------|--|--|
| Dim                  | Min   | Max   | Тур   |  |  |
| Α                    | 0.37  | 0.51  | 0.40  |  |  |
| В                    | 1.20  | 1.40  | 1.30  |  |  |
| С                    | 2.30  | 2.50  | 2.40  |  |  |
| D                    | 0.89  | 1.03  | 0.915 |  |  |
| F                    | 0.45  | 0.60  | 0.535 |  |  |
| G                    | 1.78  | 2.05  | 1.83  |  |  |
| Н                    | 2.80  | 3.00  | 2.90  |  |  |
| J                    | 0.013 | 0.10  | 0.05  |  |  |
| K                    | 0.890 | 1.00  | 0.975 |  |  |
| K1                   | 0.903 | 1.10  | 1.025 |  |  |
| L                    | 0.45  | 0.61  | 0.55  |  |  |
| L1                   | 0.25  | 0.55  | 0.40  |  |  |
| М                    | 0.085 | 0.150 | 0.110 |  |  |
| а                    | 0°    | 8°    |       |  |  |
| All Dimensions in mm |       |       |       |  |  |

## **Suggested Pad Layout**

 $Please \ see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$ 

#### SOT23



| Dimensions | Value (in mm) |  |  |
|------------|---------------|--|--|
| С          | 2.0           |  |  |
| Х          | 0.8           |  |  |
| X1         | 1.35          |  |  |
| Υ          | 0.9           |  |  |
| Y1         | 2.9           |  |  |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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